

TECHNICAL DATA DATA SHEET 825, REV. -

HERMETIC POWER MOSFET N-CHANNEL

FEATURES:

- 200 Volt, 0.045 Ohm, 50A MOSFET
- Isolated Hermetic Metal Package
- Low R_{DS (on)}

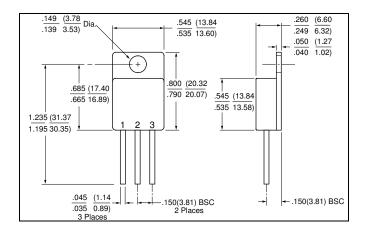
MAXIMUM RATINGS

ALL RATINGS ARE AT $T_c = 25^{\circ}C$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	V _{GS}	-	-	±20	Volts
ON-STATE DRAIN CURRENT	I _{D25}	-	-	50	Amps
PULSED DRAIN CURRENT	I _{DM}	-	-	200	Amps
OPERATING AND STORAGE TEMPERATURE	T _J /T _{STG}	-55	-	+150	С°
TOTAL DEVICE DISSIPATION	PD	-	-	270	Watts
THERMAL RESISTANCE, JUNCTION TO CASE	$R_{ extsf{ heta}JC}$	-	-	0.45	°C/W

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS
DRAIN TO SOURCE BREAKDOWN VOLTAGE	BV _{DSS}	200	-	-	Volts
$V_{GS} = 0V, I_D = 250 \mu A$					
STATIC DRAIN TO SOURCE ON STATE RESISTANCE	R _{DS(ON)}	-	-	0.045	Ω
$V_{GS} = 10V, I_D = 0.5I_{D25}$					
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	V _{GS(th)}	2.0	-	4.0	Volts
FORWARD TRANSCONDUCTANCE	g _{fs}	26	32		S(1/Ω)
$V_{\rm DS} = 10V, I_{\rm D} = 0.5I_{\rm D25}$				-	
ZERO GATE VOLTAGE DRAIN CURRENT					
$V_{DS} = 0.8 \text{ x Max. rating}, V_{GS} = 0V, T_J = 25^{\circ}C$	I _{DSS}	-	-	200	μA
$T_{\rm J} = 125^{\circ}{\rm C}$				1000	
GATE TO SOURCE LEAKAGE FORWARD V _{GS} = 20V	I _{GSS}	-	-	100	nA
GATE TO SOURCE LEAKAGE REVERSE V _{GS} = -20V				-100	
TURN ON DELAY TIME $V_{DS} = 0.5V \bullet$	t _{d(ON)}	-	18	25	
RISE TIME V_{DSS} , $I_D = 0.5 \bullet I_{D25}$	t _r		15	20	nsec
TURN OFF DELAY TIME V _{GS} =10V	t _{d(OFF)}		72	90	
FALL TIME $R_G = 1.0\Omega$	t _f		16	25	
DIODE FORWARD VOLTAGE $I_F = I_S, V_{GS} = 0V$	V _{SD}	-	-	1.5	Volts
Pulse test, t \leq 300 μ s, duty cycle d \leq 2 %	• 50				Volto
REVERSE RECOVERY TIME $T_{J} = 25^{\circ}C$,					
$I_{\rm F}=25A, V_{\rm B}=100V$	t _{rr}	-	400	-	nsec
di/dt = 100A/µsec					
INPUT CAPACITANCE $V_{GS} = 0 V$,	C _{iss}	-	4400	-	
OUTPUT CAPACITANCE $V_{DS} = 25 V$,	C _{oss}		800		pF
REVERSE TRANSFER CAPACITANCE f = 1.0MHz	C _{rss}		280		



MECHANICAL DIMENSIONS: in Inches / mm

<u>TO-254</u>

DEVICE TYPE	PIN-1	PIN-2	PIN-3
N-CHANNEL MOSFET	DRAIN	SOURCE	GATE
TO-254 PACKAGE			



TECHNICAL DATA

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